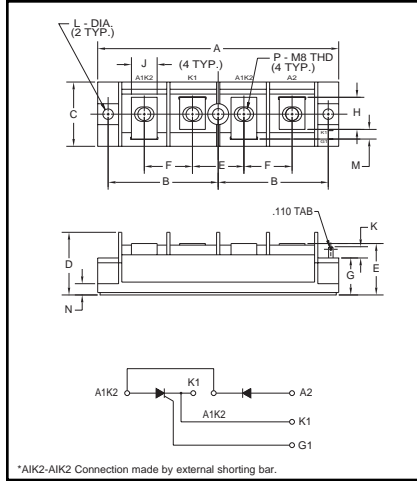


**SCR/Diode
POW-R-BLOK™ Modules
130 Amperes/1200-1600 Volts**



**CM521213, CM521613
SCR/Diode
POW-R-BLOK™ Modules
130 Amperes/1200-1600 Volts**

Outline Drawing

Dimension	Inches	Millimeters
A	5.906	150
B	2.697±0.02	68.5±0.2
C	1.575	40
D	1.535	39
E	1.260	32
F	1.181	30
G	0.906	23
H	0.787	20
J	0.630	16
K	0.276	7
L	0.256±0.008 Dia.	Dia. 6.5±0.2
M	0.236	6
N	0.197	5
P	M8 Metric	M8

Description:

Powerex SCR/Diode POW-R-BLOK™ Modules are designed for use in applications requiring Half-Control and isolated packaging. The modules are isolated for easy mounting with other components on common heatsinks.

Features:

- Isolated Mounting
- Glass Passivated Chips
- Metal Baseplate
- Low Thermal Impedance

Applications:

- Battery Supplies
- Bridge Circuits
- AC and DC Motor Control
- Tap Changers
- Lighting Control

Ordering Information:

Select the complete eight digit module part number you desire from the table below. Example: CM521613 is a 1600 Volt, 130 Ampere SCR/Diode POW-R-BLOK™ Module.

Type	Voltage Volts (x100)	Current Rating Amperes (x10)
CM52	12 16	13



Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (724) 925-7272

CM521213, CM521613
 SCR/Diode POW-R-BLOK™ Modules
 130 Amperes/1200-1600 Volts

Absolute Maximum Ratings

Characteristics	Symbol	CM521213	CM521613	Units
Peak Forward Blocking Voltage	V_{DRM}	1200	1600	Volts
Transient Peak Forward Blocking Voltage (Non-Repetitive), $t < 5ms$	V_{DSM}	1350	1700	Volts
DC Forward Blocking Voltage	$V_{D(DC)}$	960	1280	Volts
Peak Reverse Blocking Voltage	V_{RRM}	1200	1600	Volts
Transient Peak Reverse Blocking Voltage (Non-Repetitive), $t < 5ms$	V_{RSM}	1350	1700	Volts
DC Reverse Blocking Voltage	$V_{R(DC)}$	960	1280	Volts
RMS On-State Current	$I_T(RMS), I_F(RMS)$	205	205	Amperes
Average On-State Current, $T_C = 78^\circ C$	$I_T(AV), I_F(AV)$	130	130	Amperes
Peak One-Cycle Surge (Non-Repetitive) On-State Current (60Hz)	I_{TSM}, I_{FSM}	2600	2600	Amperes
Peak One-Cycle Surge (Non-Repetitive) On-State Current (50Hz)	I_{TSM}, I_{FSM}	2365	2365	Amperes
I^2t (for Fusing), 8.3 milliseconds	I^2t	28000	28000	A^2sec
Critical Rate-of-Rise of On-State Current*	di/dt	100	100	Amperes/ μs
Peak Gate Power Dissipation	P_{GM}	10	10	Watts
Average Gate Power Dissipation	$P_{G(AV)}$	3.0	3.0	Watts
Peak Forward Gate Voltage	V_{GFM}	10	10	Volts
Peak Reverse Gate Voltage	V_{GRM}	5.0	5.0	Volts
Peak Forward Gate Current	I_{GFM}	4.0	4.0	Amperes
Storage Temperature	T_{STG}	-40 to 125	-40 to 125	$^\circ C$
Operating Temperature	T_j	-40 to 125	-40 to 125	$^\circ C$
Maximum Mounting Torque M6 Mounting Screw	—	26	26	in.-lb.
Maximum Mounting Torque M8 Terminal Screw	—	72	72	in.-lb.
Module Weight (Typical)	—	300	300	Grams
V Isolation	V_{RMS}	2500	2500	Volts

* $T_j = 125^\circ C, I_G = 1.0A, V_D = 1/2 V_{DRM}$



Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (724) 925-7272

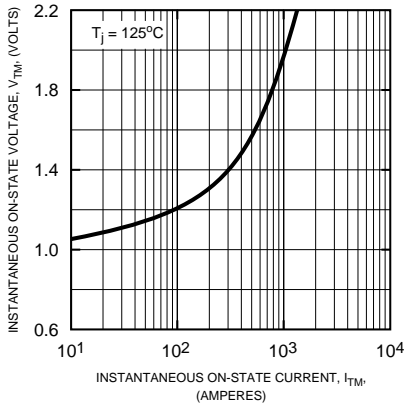
CM521213, CM521613
SCR/Diode POW-R-BLOK™ Modules
130 Amperes/1200-1600 Volts

Electrical and Thermal Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

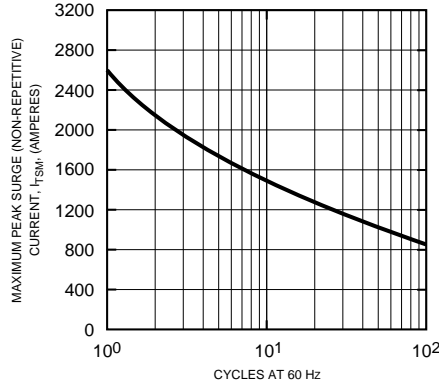
Characteristics	Symbol	Test Conditions	CM521213/CM521613	Units
Blocking State Maximums				
Forward Leakage Current, Peak	I_{DRM}	$T_j = 125^\circ\text{C}$, $V_{\text{DRM}} = \text{Rated}$	30	mA
Reverse Leakage Current, Peak	I_{RRM}	$T_j = 125^\circ\text{C}$, $V_{\text{RRM}} = \text{Rated}$	30	mA
Conducting State Maximums				
Peak On-State Voltage	V_{FM} , V_{TM}	$I_{\text{FM}} = 390\text{A}$, $I_{\text{TM}} = 390\text{A}$	1.3	Volts
Switching Minimums				
Critical Rate-of-Rise of Off-State Voltage	dv/dt	$T_j = 125^\circ\text{C}$, $V_{\text{D}} = 2/3 V_{\text{DRM}}$	500	Volts/ μs
Thermal Maximums				
Thermal Resistance, Junction-to-Case	$R_{\theta(\text{J-C})}$	Per Module	0.22	$^\circ\text{C/Watt}$
Thermal Resistance, Case-to-Sink (Lubricated)	$R_{\theta(\text{C-S})}$	Per Module	0.05	$^\circ\text{C/Watt}$
Gate Parameters Maximums				
Gate Current-to-Trigger	I_{GT}	$V_{\text{D}} = 6\text{V}$, $R_{\text{L}} = 2\Omega$	100	mA
Gate Voltage-to-Trigger	V_{GT}	$V_{\text{D}} = 6\text{V}$, $R_{\text{L}} = 2\Omega$	3.0	Volts
Non-Triggerring Gate Voltage	V_{GDM}	$T_j = 125^\circ\text{C}$, $V_{\text{D}} = 1/2 V_{\text{DRM}}$	0.25	Volts

CM521213, CM521613
SCR/Diode POW-R-BLOK™ Modules
 130 Amperes/1200-1600 Volts

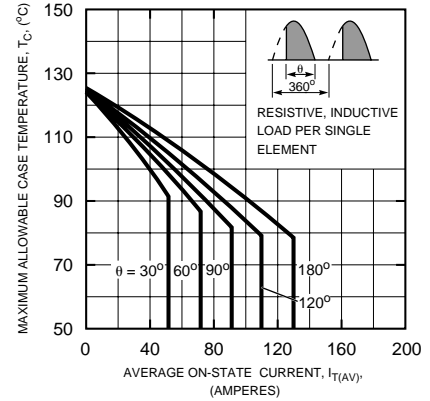
MAXIMUM ON-STATE CHARACTERISTICS



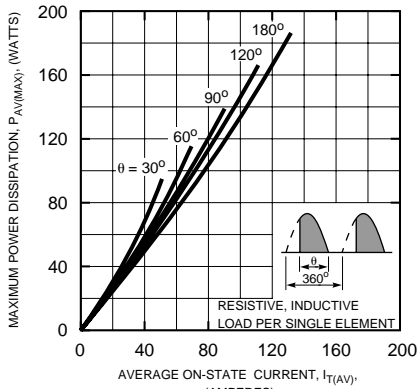
MAXIMUM ALLOWABLE PEAK SURGE (NON-REPETITIVE) CURRENT



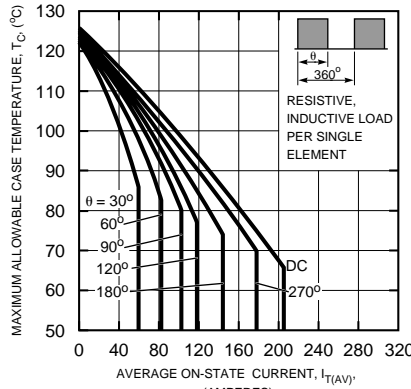
MAXIMUM ALLOWABLE CASE TEMPERATURE (SINUSOIDAL WAVEFORM)



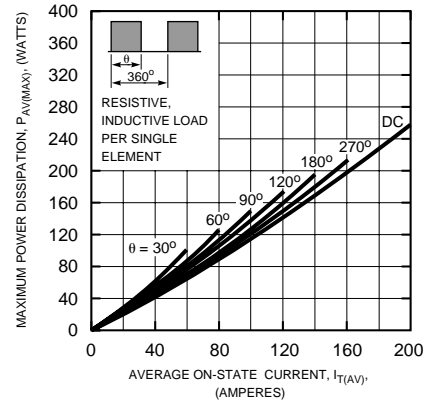
MAXIMUM ON-STATE POWER DISSIPATION (SINUSOIDAL WAVEFORM)



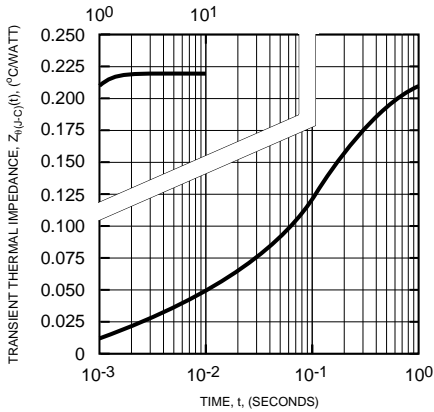
MAXIMUM ALLOWABLE CASE TEMPERATURE (RECTANGULAR WAVEFORM)



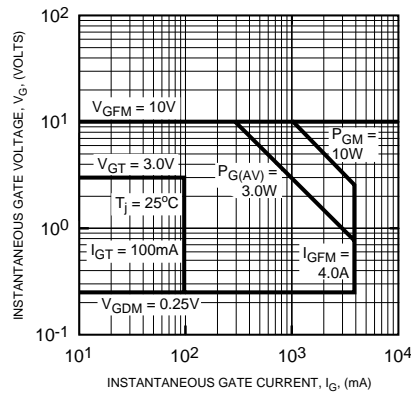
MAXIMUM AVERAGE ON-STATE POWER DISSIPATION (RECTANGULAR WAVEFORM)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (JUNCTION-TO-CASE)



TRIGGERING CHARACTERISTICS





LittleDiode supplies new, hard to find or obsolete electronic components and semiconductors all over the world.

With over two million different components listed you are sure to find the part you need.

Feel free to visit us today at our online store:

LittleDiode.com

Looking forward to providing you with the best possible service.